Electrically Conductive Oxidation-Resistant Boron-Coated Carbon Nanotubes Derived from Atmospheric CO₂ for Use at High Temperature

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ABSTRACT: This study introduces high-temperature antioxidative carbon nanotubes (CNTs) derived from carbon dioxide (CO₂). The individual CNT is coated by an amorphous boron layer that acts as a protection layer for carbon networks. It has a remarkable stability on thermal oxidation and provides a remarkable electrical conductivity of 4 S cm⁻¹ at 1000 °C, while conventional carbon-based materials, including commercial CNTs, cannot maintain electrical properties because of oxidation below 400 °C. Thus, the novel atmospheric CO₂-based chemical vapor decomposition route can contribute to the applications of carbon-based material in high-temperature oxidation conditions such as a solid oxide fuel cell.

KEYWORDS: boron-coated carbon nanotubes, CO₂ conversion, antioxidation, electrical conductivity, high temperature

High-temperature applications require materials to retain various characteristics such as thermal stability, chemical and corrosion resistance, and good electrical conductivity at extreme conditions. Therefore, it is not easy for conventional materials to satisfy all of the requirements. While single compounds of ceramics are widely used as solid oxide fuel cell (SOFC) electrode materials in the high-temperature conditions, they have a problem of exhibiting electrical conductivity only under a specific temperature range.

To overcome the limitations of typical ceramics, the strategy of combining the ceramics with carbon materials has been suggested. Among them, carbon nanotube (CNT)/ceramic composites are remarkable because of their good mechanical properties and electrical conductivity. However, it is still difficult to apply the CNT/ceramic composites at high-temperature conditions because of low antioxidative capability, which is attributed to the combustion of carbon material at temperatures higher than 500 °C. Recently, several methods to coat the inside and outside of CNTs with aluminum oxide (Al₂O₃) using atomic layer deposition (ALD) and laser-assisted chemical vapor deposition (CVD) have been proposed. The main purpose of the integration of Al₂O₃ is to protect the CNTs, which are vulnerable to oxidation or combustion at high temperature. Both cases have succeeded in improving the antioxidative capability of CNT/ceramic composites, but they require more than two complex processes as additional steps for Al₂O₃ coating.

This study introduces a novel single-step method to synthesize a boron-coated CNT (CB-CNT), which has excellent thermal stability under high-temperature oxidation conditions. On the basis of the synthesis of boron-doped porous carbon from gaseous carbon dioxide (CO₂), we demonstrate a novel CO₂-based CVD route to synthesize a CB-CNT from 1 bar of gaseous CO₂ at temperatures between 500 and 600 °C. The as-synthesized CB-CNT contains an exceptionally higher boron content at the surface than 30 atom %, and the coated boron is first oxidized at high temperature to become B₂O₃, which acts as a layer protecting the CNT from oxidation even up to 1000 °C. As a result, the unprecedented antioxidative CNT can be easily made by the one-step CO₂-based CVD route without the need for hybridization with other materials or additional complex steps. The structure of this CNT is analyzed in detail by electron microscopy, X-ray photoelectron spectroscopy (XPS), Raman spectroscopy, and electron energy loss spectroscopy (EELS). In addition, by measuring the electrical conductivity in situ under high-temperature oxidation conditions, we show for the first time...
that the CO₂-derived CB-CNT can maintain electrical conductivity in the wide temperature range, revealing an excellent electrical conductivity of 3.89 S cm⁻¹ at 1000 °C. As a result, we measured the electrical conductivity of the CB-CNT in oxidative conditions at high temperatures and verified that it was higher than those of CNT/ceramic and graphene/ceramic composites.4,5 The oxidation resistance of the electrically conductive carbon material increases the applicability of the carbon, which has already been widely used in the energy storage field,15,16 to high-temperature applications such as a SOFC.

The one-step preparation of CB-CNTs was achieved by employing sodium borohydride (NaBH₄) as a reduction agent and nickel(II) chloride (NiCl₂) as a precursor for nickel nanoparticles, as illustrated in Figure 1a. The origin of the synthesis of the CB-CNT is the deposition of methane, which is the product of reduction of CO₂ by a reducing agent,17 onto nickel particles based on in situ gas analyses on the real-time synthesis process (Figure S1).

The scanning electron microscopy (SEM) image indicated that the CB-CNT developed CNT fibers (Figure 1b). It stretched from 150 μm to 1.88 mm in length, and its diameter ranged from 7.5 to 16 μm (Figure S2). The CB-CNT had a bundle of smaller fibers, and the fibers were highly populated (Figure 1b,c). The CB-CNT fibers were suspended in ethanol and sonicated for about 1 h to investigate an individual CNT by separating it from the fibers before the transmission electron microscopy (TEM) observations. The individual CNT was present in the form of a multiwalled carbon nanotube (MWCNT), which had more than 20 walls (Figure 1d). The fast Fourier transform (FFT) pattern on the wall showed the typical properties of a MWCNT with crystallinity in the (002) direction and an interlayer distance between (002) planes of 0.35 nm (insets of Figure 1d).18

XPS is performed to investigate the surface elemental composition of the CB-CNT, as listed in Table 1 and Figure S3 and Tables S1 and S2. According to the XPS survey results, the CB-CNT contained an amount of boron close to 30 atom % (Table 1 and Figure S3a). This content is exceptionally high compared to previous studies that showed 2.07−7.87% of doped boron (a detailed comparison is listed in Table S3).19−23 In fact, among the peaks obtained by deconvoluting the high-resolution spectra for C 1s, the C−B bonding peak was found at around 283.8 eV (Figure S3b). Moreover, the spectra for B 1s indicated that the boron exists in the form of C−B bonding, not in an elemental form, based on several peaks, such as B₄C (∼187.8 eV), BC₃ (∼189.3 eV), and BCO₂ (∼192.5 eV) (Figure S3c).25 Specifically, B₄C is the dominant C−B bonding in the CB-CNT (Tables S1 and S2).

To confirm where 30 atom % boron exists in the CB-CNT, a high-resolution TEM (HRTEM) image was obtained, as shown in Figure 2a, and an amorphous layer was found outside the graphene layer. The composition of this amorphous layer was verified by EELS by a line scanning perpendicular to the individual CNT axis (Figure 2b). At the line profiling of carbon and boron for each location (Figure 2c), the carbon was distributed along with the tube, but the distribution of boron was quite remarkable because the signal indicated that the boron was distributed along the outer surface of the CNT as in the carbon coated with boron, which indicates that the amorphous layer in the HRTEM image is related to the boron. Such results allowed us to surmise that

Table 1. Summary of the Surface Elemental Composition of the CB-CNT Based on the XPS Survey Results

<table>
<thead>
<tr>
<th>sample</th>
<th>C 1s (atom %)</th>
<th>O 1s (atom %)</th>
<th>B 1s (atom %)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CB-CNT</td>
<td>49.29 (2.80)</td>
<td>16.96 (0.37)</td>
<td>33.75 (3.54)</td>
</tr>
<tr>
<td>CB-CNT (after oxidation at 900 °C)</td>
<td>15.80 (3.05)</td>
<td>64.69 (2.50)</td>
<td>19.51 (0.60)</td>
</tr>
</tbody>
</table>

The standard deviation (SD) is in parentheses.

Figure 1. (a) Schematic illustration for the synthetic route of the CB-CNT based on CO₂-based CVD. (b) SEM image of the CB-CNT. (c) TEM image of the CB-CNT and (d) its high-magnification version [insets: FFT pattern and interlayer spacing of carbon (002)].
Figure 2. (a) HRTEM image. (b) Scanning TEM image of the CB-CNT to obtain the EELS spectra (the green line indicates the location for the EELS line profiling). (c) Overlay of the carbon and boron signals from the EELS line profiling depending on the location. (d–f) EELS spectra of each element depending on the location.

Figure 3. (a) TGA plots of the CB-CNT and commercial MWCNT in air. (b) Comparison of B 1s plots between the CB-CNT and its residue after oxidation up to 900 °C. (c) Comparison of the Raman spectra between the CB-CNT and its residue after oxidation up to 900 °C. (d) Schematic diagram for the experiment to measure the electrical conductivity of the sample under high-temperature oxidation. (e) Comparison of the state of pellets between the CB-CNT and MWCNT after measurement up to 900 °C. (f) Calculated electrical conductivity depending on the temperature (the error bars and a detailed determination for the CB-CNT data are shown in Figure S5).
the CB-CNT was produced from CO₂ via the NaBH₄-based CVD method. This coated boron can contribute to the high amount of boron that was detected in the XPS survey results of the CB-CNT, and its bonding type in the interface between the graphene and amorphous boron layers is likely to be a hybrid of B₄C and BC₃, as confirmed by the deconvoluted B 1s spectra of XPS (Figure S3c). In addition, the EELS spectra for boron (Figure 2e) supported the existence of B₄C and BC₃ by showing that the well-developed π* and σ* peaks were observed only in the interface (marked as A and E in Figure 2e), while the π* and σ* peaks in the C–K edge were observed throughout the profiling line (Figure 2d). In BCO₂, it can be negligible because there was a very weak signal for the oxygen atom without the developed type of π* and σ* peaks in the EELS line profiling (Figure 2f).

We performed thermogravimetric analysis (TGA) to elucidate the thermal and antioxidative properties of the CB-CNT. The thermal oxidation behavior of the CB-CNT is distinctly different from that of the conventional carbon materials, as shown in Figure 3a. In general, amorphous carbon decomposes at 300–400 °C, and crystalline carbon, including graphene and CNTs, decomposes at about 500 °C in an oxidizing atmosphere. As a result, both of the carbon materials disappear above 800 °C and show near zero weight,²⁶ as verified in the case of the commercial MWCNT (the blue plot in Figure 3a). However, the CB-CNT remains over 80% even after 900 °C, which is the highest retention rate in CNT-based materials (≈36%), including graphene (under 10%) measured by TGA for antioxidative capability in air.

To investigate the origin of the unusual thermal oxidation stability revealed in TGA, we performed XPS analysis on the residue from the CB-CNT after thermal oxidation up to 900 °C. There was approximately 15 atom % carbon (Table 1), which meant that the carbon networks were preserved under high-temperature oxidation. Interestingly, the state of boron changed from B₀C, BC₃, and BCO₂ (the black line in Figure 3b) to boron oxide close to B₂O₃ based on the B 1s graphs and a binding energy of about 194 eV (the red line in Figure 3b).²⁷ This result suggested that the boron coating can affect the unique behavior of the superior antioxidative capability. The rich boron covering the CNT would oxidize at 200 °C and become boron oxide (B₂O₃), which contributed to an increase in the mass of the CB-CNT due to the incorporated oxygen, as in the case of the coating on a diamond.²⁷ Then above 400 °C, the B₂O₃ layer protected the carbon atoms from thermal decomposition, but there was also decomposition of carbon atoms without the B₂O₃ layer, which reduced the mass after 400 °C in the TGA plot. As a result, the B₂O₃ layer acted as a protective layer to increase the stability of the carbon from thermal oxidation.²⁷ Therefore, the CB-CNT showed a retention of more than 80%. In particular, the protection system by the B₂O₃ layer worked effectively on the synthesized CNTs that were coated with boron. Raman analyses on the residues showed that the structure of the CNT was preserved well after thermal oxidation at 900 °C, based on the apparent D, G, and 2D bands (Figure 3c). In addition, because the amorphous carbon without the boron protection layer gasified, the Raman spectrum of the CB-CNT became close to that of pure MWCNTs, which had sharper and more intensified bands than the original CB-CNT (the red line in Figure 3c).²⁸ The SEM image of the residue supports the existence of CNTs by showing the preserved CNT shape and the fiber shape (Figure S4). These outstanding thermal characteristics confirm that the CB-CNT can be applied to high-temperature oxidation conditions.

To ensure application of the CB-CNT to high-temperature oxidation conditions, the electrical conductivity depending upon the temperature ramping was obtained with four-probe current–voltage (I–V) curve measurement on pelletized CB-CNT in a furnace (Figure 3d), and it is summarized in Figure 3f. The CB-CNT at room temperature had a lower electrical conductivity than the commercial MWCNT because the CB-CNT had a large amount of boron and oxygen (ca. 50 atom % in Table 1), which were less electrically conductive than the pure CNTs.²⁸ Above 400 °C, the MWCNT began to decompose, so the pellet collapsed (Figure 3e), and measurement was impossible. With the CB-CNT, however, the B₂O₃ layer protected most of the carbon networks, including the CNT. Therefore, the CB-CNT was able to maintain the electrical conductivity over 400 °C. At 550 °C, the conductivity of the CB-CNT in an air atmosphere reached 0.45 S cm⁻¹, which was superior to those of vertically aligned CNTs/Al₂O₃ (0.089 S cm⁻¹ measured at 550 °C in nitrogen). After 450 °C, there was a decrease in the electrical conductivity, which we saw as the effect of the phase change of B₂O₃ because the temperature corresponded to its melting point. However, the CB-CNT became stable, and the electrical conductivity increased sharply. At 650 °C, the electrical conductivity of the CB-CNT exceeded 1.02 S cm⁻¹ of graphene/Al₂O₃,²⁹ which was measured at room temperature. Consequently, it is remarkable that the CB-CNT provides stable electrical conductivity even at 1000 °C at about 4 S cm⁻¹. To the best of our knowledge, our study introduced for the first time the implementation and measurement of the electrical conductivity up to 1000 °C under oxidation environments for carbon-based composites. In addition, the CB-CNT demonstrated competitive electrical conductivity superior to other carbon/ceramic composites at high temperatures. After reaching 1000 °C in air, the temperature was maintained for 12 h at the same conditions to identify the thermal stability of the CB-CNT. Then, the electrical conductivity was measured while the temperature decreased in air (the red square in Figure 3f). While the electrical conductivity slightly decreased according to the temperature decrease, the CB-CNT still maintained a high electrical conductivity of 1.7 S cm⁻¹ when it returned to room temperature. Typical high-temperature electrochemical applications, SOFC and protonic ceramic fuel cell (PCFC), require electrode materials (SOFC, anode; PCFC, cathode) to have more than 1 S cm⁻¹ during the high-temperature operation.²⁹,³⁰ As a result, the CB-CNT can meet the requirements, which indicates that the CB-CNTs have the potential to be used as electrode materials in high-temperature electrochemical devices.

We have synthesized CB-CNTs with a high boron amount of 30% using CO₂ as the carbon source. Because the boron coating layer acted as a protective layer of carbon atoms against thermal oxidation first by oxidizing to become B₂O₃, and the CB-CNT endured above 900 °C. Therefore, the CB-CNT represents a competitive electrical conductivity even up to 1000 °C (ca. 4 S cm⁻¹). This unique high-temperature stability confirmed that carbon-based materials can be applied to high-temperature oxidation environments including the SOFC.
ASSOCIATED CONTENT

Supporting Information
The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsanm.0c01909.
Experimental sections, including preparation and characterization of the CB-CNT and conductivity measurements, supporting figures, including the synthesis mechanism of CB-CNT, and supporting tables (PDF).

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Notes
The authors declare no competing financial interest.

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